V3.1 High configuration							
Date:	2023-8-19	Writer :					
BOM 3.1	Revision : Rev						
NO.	Package	Parts Type	Specification	QI V	Position		
Main-\	/3.1						
1	SMT	Resistance	$1/16$ W $-0~\Omega~\pm 5$ % -0402	8	L1-L2, C15, R37, R54, R66, R71, R79		
2	SMT	Resistance	$1/16W-1K\Omega \pm 5\%-0402$	7	R2, R5, R11, R60, R62, R65, R74		
3	SMT	Resistance	$1/16$ W -10 K $\Omega \pm 5$ % -0402	7	R9-R10, R12, R39, R59, R73, R78		
4	SMT	Resistance	$1/16$ W -100 K $\Omega \pm 5$ % -0402	10	R1, R3, R23, R47, R49, R58, R63–R64, R82, R87		
5	SMT	Resistance	$1/16$ W -2 K $\Omega \pm 5$ % -0402	1	R61		
6	SMT	Resistance	$1/16$ W-22 $\Omega \pm 5$ %-0402	27	R6-R8, R15-R21, R24-R26, R28-R29, R33-R36, R38, R40- R41, R51-R52, R75-R77		
7	SMT	Resistance	$1/16$ W $-33~\Omega~\pm 5$ % -0402	2	R55-R56		
8	SMT	Resistance	$1/16$ W-4. 7K $Ω \pm 5$ %-0402	7	R13-R14, R22, R43, R48, R50, R53		
9	SMT	Resistance	$1/16$ W-49. 9 $\Omega \pm 1$ %-0402	1	R70		
10	SMT	Resistance	$1/10$ W -0 $\Omega \pm 5$ % -0603	1	R57		
11	SMT	Resistance	$1/16$ W -100 K $\Omega \pm 1$ % -0402	1	R68		
12	SMT	Resistance	$1/16$ W -1 M $\Omega \pm 1$ % -0402	7	R4, R31, R42, R44, R81, R83-R84		
13	SMT	Resistance	$1/16$ W -510 K $\Omega \pm 1$ % -0402	1	R69		
14	SMT	Resistance	$1/16$ W -680 K $\Omega \pm 5$ % -0402	1	R30		
15	SMT	Resistance	$1/16$ W -300 K $\Omega \pm 1$ % -0402	1	R32		
16	SMT	Resistance	$1/16$ W-4. 99 $\Omega \pm 1$ %-0402	1	R72		
17	SMT	Resistance	$1/16$ W-76. 8k $\Omega \pm 1$ %-0402	1	R27		
18	SMT	Capacitance	16V-0.1uF±10%-X7R-0402	17	C7, C13-C14, C19, C21, C24, C29, C31, C34, C45, C51- C52, C58, C74, C86, C97, C110		
19	SMT	Capacitance	$50V-10pF \pm 5\%-NPO-0402$	1	C89		
20	SMT	Capacitance	$50V-22pF \pm 5\%-NPO-0402$	2	C43, C48		
21	SMT	Capacitance	50V-33pF±5%-NPO-0402	2	C62-C63		
22	SMT	Capacitance	25V-0.01uF±10%-X7R-0402	5	C4, C6, C56, C64, C71		

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23	SMT	Capacitance	16V-0. 1uF+80/-20%-Y5V-0402	25	C1, C5, C9, C11, C35–C36, C38, C41–C42, C53, C55, C66– C67, C69, C73, C75–C78, C81–C83, C88, C90, C98
24	SMT	Capacitance	$50V-18pF \pm 5\%-NPO-0402$	4	C17-C18, C46-C47
25	SMT	Capacitance	$50V-1UF \pm 10\%-X7R-0603$	1	C100
26	SMT	Capacitance	16V-1UF-10%-X5R-0402	10	C23, C26–C27, C30, C37, C39–C40, C80, C85, C87
27	SMT	Capacitance	$50V-2pF\pm 0.25PF-NP0-0402$	1	C8
28	SMT	Capacitance	6. 3V-10uF±20%-X5R-0402	14	C2, C10, C12, C25, C32, C49– C50, C54, C57, C61, C65, C68, C84, C99
29	SMT	Capacitance	10V-2. 2uF±20%-X5R-0402	3	C20, C22, C28
30	SMT	Capacitance	$25V-330nF \pm 10\%-X7R-0402$	1	C79
31		Inductance	$10 \text{uH} \pm 20\%$ -0. 75A-2. 5x2. 0x1. 2mm-SMD (NR252012-100M)	1	L4
32	SMT	Inductance	2. 2uH+/-20%-950mA-0805 (CMH201209B2R2MT)	1	L3
33	SMT	Crystal	12. $000 \text{MHz} \pm 10 \text{PPM} - 18 \text{pF} - 3225 \text{ (JY} - 3225 - 12.000 - 18)$	1	Х3
34	SMT	Crystal	32. 768KHz+/-20PPM-12. 5pF-3215-2PAD (CM315D32768DZFT)	1	X2
35	SMT	Crystal	24.000MHz ± 10PPM-18pF-SMD3225 (SMD3225-24.000M-18)	1	X1
36	SMT	Diode	RB520S30T1G-30V-S0D523	7	D1-D2, D10-D11, D13, D17, D22
37	SMT	ESD	ESD-12V-0402(ESDPSA0402V12/Semitel)	2	D23-D24
38	SMT	ESD	ESD-5V-0402 (D1006WV05C005BT)	3	D15, D18, D38
39	SMT	Diode	B5819W-40V-1A-SOD-123	2	D16, D37
40	SMT	ESD	ESD-3.3V-0402 (D1006WV033C003BT)	22	D3-D9, D12, D19-D20, D25-D36
41	SMT	Transistor	S9013-NPN-Transistor-40V-0.3W-0.5A-hFE-H S0T23	1	Q7
42	SMT	Transistor	DTC114EE-NPN-SOT523	2	Q10-Q11
43	SMT	Transistor	CJ2301-P-Channel MOSFET 20Vds-S0T23(JCST)	5	Q1, Q4-Q5, Q8-Q9
44	SMT	Transistor	CJ2310-60V-3A-N-Channel-MOSFET-SOT23(JCST)	3	Q2-Q3, Q6
45	SMT	Battery	CR2016-3V-battery-SMD	1	BAT1
46	SMT	Switch	YST-1112A-Switch-SMD-ppa-5kg	1	S2
47	SMT	IC	LP3987H-33B5F-3.3V-600mA-LD0-S0T-23-5(LP Semi)	3	U2, U12-U13
48	SMT	IC	SGM3726YTN6G- LED Driver-20V Input-TSOT23-6(SGMICRO)	1	U15
49	SMT	IC	ME6119C33M5G-3.3V-400mA-LDO-SOT23-5(Microne)	1	U1
50	SMT	IC	MH1903-BGA169 (MEGAHUNT)	1	U7
51	SMT	IC	APS6404L3SQR-SN-SOP8 (apmemory)	1	U11
52	SMT	IC	PY25Q128HA-SUH-IT-SO8N(Puya Semiconductor)	2	U8-U9

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53			DS28S60Q+-TDFN12(Maxim)	1	U4
54	SMT	IC	BR8051A01-QFN32 (BARROT)	1	U3
55	SMT	IC	ATECC608B-SSHDA-T(Microchip)	1	U10
56	SMT	IC	AW32001ECSR-WLCSP-9B (AWINIC)	1	U5
57	SMT	IC	MAX32520-BNS+T-TQFN32(Maxim)	1	U6
58	SMT	Connector	3PIN-1.25mm-Socket-SMT	1	J4
59	SMT	Connector	24PIN-0.4mm-Female-HO.8mm-SMD(OK-14F024-04/OCN)	1	J1
60	SMT	Connector	10PIN-0.4mm-Male-HO.8mm-SMD(OK-14F010-04/OCN)	1]3
61	SMT	Connector	40PIN-0.5mm-Female-H2.5mm-SMD (HTT-BM7340-0525-G01)	1	Ј13
62	SMT	Connector	1PIN-Antenna RF Spring-2.5x1.2x2.6mm-SMD(PSC112-40260-7R)	4	J5–J7, J9
63	SMT	Connector	MicroSD-Socket-SMD(E6502-1)	1	Ј12
64	DIP	PCB	MainPro-V3.1	1	
PORT-	V3.1				
1	SMT	Resistance	$1/16$ W-0 $\Omega \pm 5$ %-0402	2	R10-R11
2	SMT	Resistance	$1/16$ W -33 K $\Omega \pm 5$ % -0402	1	R2
3	SMT	Resistance	$1/16 \text{W-}120 \text{K} \ \Omega \ \pm 1 \text{\%-}0402$	1	R1
4	SMT	Resistance	$1/16W-5$. $1K \pm 1\%-0402$	2	R12, R13
5	SMT	Capacitance	$16V-0.1uF \pm 10\%-X7R-0402$	1	C4
6	SMT	Capacitance	$50V-22pF \pm 5\%-NPO-0402$	1	C5
7	SMT	Capacitance	16V-1UF-10%-X5R-0402	2	C1-C2
8	SMT	Capacitance	6. 3V-10uF±20%-X5R-0402 (CL05A106MQ5NUN/Samsung)	1	C6
9	SMT	ESD	ESD-5V-0402 (D1006WV05C005BT)	1	D11
10	SMT	ESD	ESD-12V-0402(ESDPSA0402V12/Semitel)	1	D9
11	SMT	ESD	ESD-3. 3V-0402 (D1006WV033C003BT)	2	D2-D3
12	SMT	IC	WS3222D-6.8V-OVP-DFN2x2-8L (WS3222D-8/TR-will)	1	U1
	SMT		24PIN-USB3.0-TYPE C-SMD (UA2401050316-104/D-CHAIN)		Ј1